

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Kirk D. Prall, et al.

Serial No:

Filed: February 14, 2000

For: RANDOM ACCESS MEMORY

) Attorney

) Docket Number: MICR131.02

) Group Art Unit:

) Examiner: -

February 14, 2000

Assistant Commissioner of Patents  
Washington, DC 20231

Sir:

**PRELIMINARY AMENDMENT**

Please amend the Application as follows.

**In The Specification**

Change the title to read -RANDOM ACCESS MEMORY--

**--Cross Reference to Related Applications**

This is a division of Application Serial No. 08/868,058 filed June 3, 1997,  
which is a continuation of Application Serial No. 08/399,843 filed March 7, 1995.

**In The Claims**

Please cancel all of the existing Claims 1-22 and add the following new  
claims. These new claims are identical to Claims 32-38 which were canceled in the  
parent case as being drawn to a non-elected invention.

23.(new) A semiconductor memory device, comprising:

a silicon structure having a first conductivity type;

a gate electrode over the silicon structure;

a capacitor contact region in the silicon structure adjacent to one side of the

gate electrode;

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08/868,058

*Stevenson*  
*6211007*  
*5650349*